



AMP2056B SOLID STATE HIGH POWER AMPLIFIER

FEATURES

- Designed for HF high power applications
- Class AB linear LDMOS design
- Rack mounted system
- Instantaneous wide bandwidth
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness



ELECTRICAL SPECIFICATIONS: 50 Ω, 25 °C

Parameter	Specification	Notes
Operating Frequency Range	3 - 30 MHz	
Power Output	1000 Watt Min	CW
Power Gain	60 dB Min	
Power Gain Flatness	3.0 dB p-p Max	
Input Return Loss	-10 dB Max	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	<-30dBc Typ	50dBm/Tone, Δ = 1MHz
Harmonics	<-20 dBc Typ	
Spurious	-60 dBc Min	Non-harmonics
Operating Voltage	180 - 240 VAC	50-60 Hz - Single phase
Power Consumption	3000 Watt Max	At rated Pout
Input Power Protection	+8 dBm Max	<10 Sec without damage
Load VSWR Protection	5 : 1 Max	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50°C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 133 x 560 mm	3U
Weight	25 Kg. Max	
RF Connectors In/Out	Type-N female	Front or rear panel
AC Power	MS3102A22-22P	
I/O Connector	9-Pin D-Sub	See Table
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485 Optional GPIB Interface	Remote Bluetooth application
OPTIONAL: Output Sample Port	SMA (F)	Front or Rear panel

D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	N/C	N/A
2	N/C	N/A
3	DC Current Sensor	$I_D @ 20mV/100mA$ Typ
4	Temp Sensor	$V_T @ 10mV/^{\circ}C + 500mV$ Typ
5	Shutdown	TTL
6	DC Voltage Sensor	Internal PS voltage
7	N/C	N/A
8, 9	GND	

OUTLINE DRAWING

